REISSUE APPLICATION DECLAPATION BY THE INVENTOR

Docket Number

DECLA	251272US2S RE		
I believe I am the origina	address and citizens	hat: hip are stated below next to my nai entor (if only one name is listed to of the subject matter which is de	pelow) or an original first and join
Patent Number		Date Patent Issued	
6,346,464		February 12, 2002	
Title of Invention	100 OF 0514160115	NICTOR DEVICE	
MANUFACTURING METH			
for which a reissue patent			
MANUFACTURING METH	IOD OF SEMICOND	OUCTOR DEVICE	
the specification of which			
is attached hereto			40/047 800
was filed on April 5		_ as reissue application number	10/8 7,623
and (If applicable) wa	s amended on	April 5, 2004	- .
by any amendment referre	d to above.	of the above-identified specification	
_		which is material to patentability as	
patent or inventor's certific other than the United Sta	ate, or §365(a) of an ates, listed below a CT international app	nder 35 USC §119(a)-(d) or §365(by PCT International application wh nd have also identified below an plication having a filing date befor	ich designated at least one country y foreign application for patent or
Application No.	Country	Day/Month/Year	Priority Claimed
11-181687	JAPAN	28 JUNE 1999	YES
		§119(e) of any United States <i>provi</i> s	
Ap	plication Number	. Filin	g Date
International application de claims of this application is provided by the first paragi	esignating the United s not disclosed in the raph of 35 USC §112 37 CFR §1.56 which	SC §120 of any United States ap I States, listed below and, insofar a e prior United States or PCT Inter 2, I acknowledge the duty to disclo become available between the filings application.	is the subject matter of each of the matter application in the manner use information which is material to
Application Se	∍rial No.	Filing Date	Status
6,346,46	4	12 February 2002	Patented
I verily believe the original (Check all that apply)	patent to be wholly o	r partly inoperative or invalid, for th	e reasons described below.
□ by reason of a defective	ve specification or dr	awing.	
by reason of the pater	itee claiming more o	r less than he had the right to claim	n in the patent (see below).
□ by reason of other error	ors (see below).	-	•
junction structure compri conductivity-type region a that have been added to (tional limitations of ising a vertical junc are alternatively arr Claims 1, 2, and 12.	f "wherein the irradiating impurit tion group where a first conduct ranged vertically to a surface of t	livity-type region and the second the semiconductor substrate"
An entitis corrected in this h	aissue application ar	ose without any deceptive intentior	on the part of the applicant.

As a named inventor, I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected herewith:

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I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine and imprisonment, or both, under 18 U.S.C. 1001, and that such willful false statements may jeopardize the validity of the application, any patent issuing thereon, or any patent to which this declaration is directed.

or any patent to which this declaration is directed.			
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Signature	Date		
Residence	Citizenship		
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